



Product Overview

2N5190: 4.0 A, 40 V NPN Bipolar Power Transistor

For complete documentation, see the data sheet

Product Description

The Power 4 A, 80 V Bipolar NPN Transistors is for use in power amplifier and switching circuits. This transistor has excellent safe area limits and is a complement to PNP 2N5194, 2N5195

Features

- Pb-Free Packages are Available

Part Electrical Specifications

Product	Compliance	Status	Polarity	I _C Continuous (A)	V _{(BR)CEO} Min (V)	h _{FE} Min	h _{FE} Max	f _T Min (MHz)	P _{TM} Max (W)	Package Type
2N5190G	Pb-free Halide free	Active	NPN	4	40	25	100	2	40	TO-225-3

For more information please contact your local sales support at www.onsemi.com

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